



ACS08MS

Radiation Hardened Quad 2-Input AND Gate

July 1998

Features

- QML Qualified Per MIL-PRF-38535 Requirements
- 1.25Micron Radiation Hardened SOS CMOS
- Radiation Environment
 - Latch-up Free Under any Conditions
 - Total Dose 3×10^5 RAD(Si)
 - SEU Immunity $<1 \times 10^{-10}$ Errors/Bit/Day
 - SEU LET Threshold $>100\text{MeV}/(\text{mg}/\text{cm}^2)$
- Input Logic Levels ... $V_{IL} = (0.3)(V_{CC})$, $V_{IH} = (0.7)(V_{CC})$
- Output Current $\pm 8\text{mA}$ (Min)
- Quiescent Supply Current $100\mu\text{A}$ (Max)
- Propagation Delay 15ns (Max)

Applications

- High Speed Control Circuits
- Sensor Monitoring
- Low Power Designs

Description

The Radiation Hardened ACS08MS is a Quad 2-Input AND Gate. For each gate, a HIGH level on both the A and B inputs results in a HIGH level on the Y output. A LOW level on either the A or B input results in a LOW level on the Y output. All inputs are buffered and the outputs are designed for balanced propagation delay and transition times.

The ACS08MS is fabricated on a CMOS Silicon on Sapphire (SOS) process, which provides an immunity to Single Event Latch-up and the capability of highly reliable performance in any radiation environment. These devices offer significant power reduction and faster performance when compared to ALSTTL types.

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

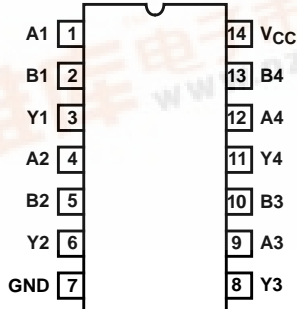
Detailed Electrical Specifications for the ACS08 are contained in SMD 5962-95651. A "hot-link" is provided on our homepage with instructions for downloading. www.intersil.com/data/sm/index.asp

Ordering Information

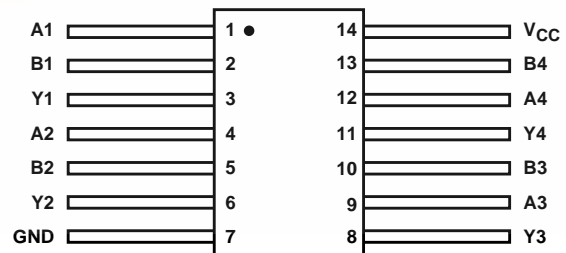
| ORDERING NUMBER | INTERNAL MARKETING NUMBER | TEMP. RANGE (°C) | PACKAGE | DESIGNATOR |
|-----------------|---------------------------|------------------|----------------|------------|
| 5962F9565101VCC | ACS08DMSR | -55 to 125 | 14 Ld SBDIP | CDIP2-T14 |
| ACS08D/SAMPLE | ACS08D/SAMPLE | 25 | 14 Ld SBDIP | CDIP2-T14 |
| 5962F9565101VXC | ACS08KMSR | -55 to 125 | 14 Ld Flatpack | CDFP4-F14 |
| ACS08K/SAMPLE | ACS08K/SAMPLE | 25 | 14 Ld Flatpack | CDFP4-F14 |
| 5962F9565101V9A | ACS08HMSR | 25 | Die | N/A |

Pinouts

ACS08 (SBDIP)
TOP VIEW



ACS08 (FLATPACK)
TOP VIEW



ACS08MS

Die Characteristics

DIE DIMENSIONS:

Size: 2390 μ m x 2390 μ m (94 mils x 94 mils)
Thickness: 525 μ m \pm 25 μ m (20.6 mils \pm 1 mil)
Bond Pad: 110 μ m x 110 μ m (4.3 mils x 4.3 mils)

METALLIZATION: Al

Metal 1 Thickness: 0.7 μ m \pm 0.1 μ m
Metal 2 Thickness: 1.0 μ m \pm 0.1 μ m

SUBSTRATE POTENTIAL:

Unbiased Insulator

PASSIVATION

Type: Phosphorous Silicon Glass (PSG)
Thickness: 1.30 μ m \pm 0.15 μ m

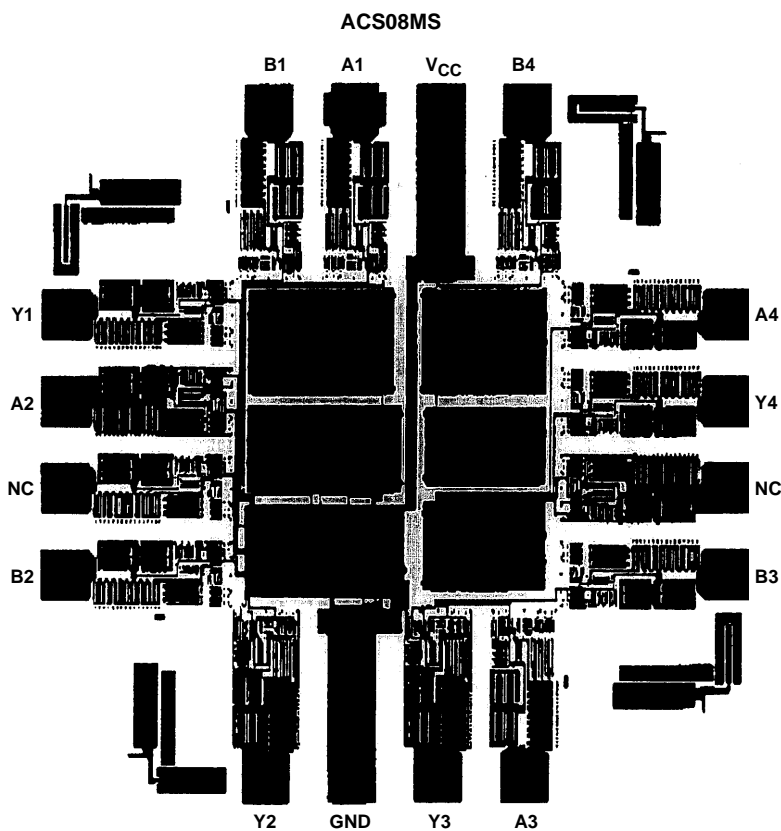
SPECIAL INSTRUCTIONS:

Bond V_{CC} First

ADDITIONAL INFORMATION:

Worst Case Density: $<2.0 \times 10^5$ A/cm²
Transistor Count: 176

Metallization Mask Layout



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